## Darlington Amplifier Transistors

NPN Silicon

## MMBTA13L, SMMBTA13L, MMBTA14L, SMMBTA14L

## Features

- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant*


## MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
| :--- | :---: | :---: | :---: |
| Collector-Emitter Voltage | $\mathrm{V}_{\mathrm{CES}}$ | 30 | Vdc |
| Collector - Base Voltage | $\mathrm{V}_{\mathrm{CBO}}$ | 30 | Vdc |
| Emitter-Base Voltage | $\mathrm{V}_{\text {EBO }}$ | 10 | Vdc |
| Collector Current - Continuous | $\mathrm{I}_{\mathrm{C}}$ | 300 | mAdc |

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
| :--- | :---: | :---: | :---: |
| Total Device Dissipation FR-5 Board <br> (Note 1) $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ | $\mathrm{P}_{\mathrm{D}}$ | 225 | mW |
| Derate above $25^{\circ} \mathrm{C}$ |  |  |  |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. $\mathrm{FR}-5=1.0 \times 0.75 \times 0.062 \mathrm{in}$.
2. Alumina $=0.4 \times 0.3 \times 0.024 \mathrm{in} .99 .5 \%$ alumina.

ON Semiconductor ${ }^{\text {® }}$
www.onsemi.com
SOT-23 (TO-236)

## MARKING DIAGRAM



1x = Device Code
X = M for MMBTA13LT1G,
SMMBTA13LT1G
$\mathrm{x}=\mathrm{N}$ for MMBTA14LT1G,
SMMBTA14LT1G, T3G
M = Date Code*

- = Pb-Free Package
(Note: Microdot may be in either location)
*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

| Device | Package | Shipping $^{\dagger}$ |
| :--- | :---: | :---: |
| MMBTA13LT1G, <br> SMMBTA13LT1G | SOT-23 <br> $($ Pb-Free $)$ | $3,000 /$ Tape \& Reel |
| MMBTA14LT1G, <br> SMMBTA14LT1G | SOT-23 <br> (Pb-Free) | $3,000 /$ Tape \& Reel |
| SMMBTA14LT3G | SOT-23 <br> (Pb-Free) |  <br> Reel |

$\dagger$ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## MMBTA13L, SMMBTA13L, MMBTA14L, SMMBTA14L

ELECTRICAL CHARACTERISTICS $\left(\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}\right.$ unless otherwise noted)

| Characteristic | Symbol | Min | Max | Unit |
| :---: | :---: | :---: | :---: | :---: |
| OFF CHARACTERISTICS |  |  |  |  |
| Collector-Emitter Breakdown Voltage ( $\mathrm{IC}_{\mathrm{C}}=100 \mu \mathrm{Adc}, \mathrm{V}_{\mathrm{BE}}=0$ ) | $\mathrm{V}_{\text {(BR) }}$ CES | 30 | - | Vdc |
| Collector Cutoff Current $\left(\mathrm{V}_{\mathrm{CB}}=30 \mathrm{Vdc}, \mathrm{I}_{\mathrm{E}}=0\right)$ | $\mathrm{I}_{\text {cbo }}$ | - | 100 | nAdc |
| Emitter Cutoff Current $\left(\mathrm{V}_{\mathrm{EB}}=10 \mathrm{Vdc}, \mathrm{I}_{\mathrm{C}}=0\right)$ | $\mathrm{I}_{\text {ebo }}$ | - | 100 | nAdc |

ON CHARACTERISTICS (Note 3)

| DC Current Gain <br> $\left(\mathrm{I}_{\mathrm{C}}=10 \mathrm{mAdc}, \mathrm{V}_{\mathrm{CE}}=5.0 \mathrm{Vdc}\right)$ <br> MMBTA13, SMMBTA13 <br> MMBTA14, SMMBTA14 <br> $\left(\mathrm{I}_{\mathrm{C}}=100 \mathrm{mAdc}, \mathrm{V}_{\mathrm{CE}}=5.0 \mathrm{Vdc}\right)$ <br> MMBTA13, SMMBTA13 <br> MMBTA14, SMMBTA14 | $\mathrm{h}_{\text {FE }}$ | $\begin{gathered} 5000 \\ 10,000 \\ \\ 10,000 \\ 20,000 \end{gathered}$ | $\begin{aligned} & \text { - } \\ & \text { - } \end{aligned}$ | - |
| :---: | :---: | :---: | :---: | :---: |
| Collector-Emitter Saturation Voltage ( $\mathrm{I}_{\mathrm{C}}=100 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B}}=0.1 \mathrm{mAdc}$ ) | $\mathrm{V}_{\text {CE(sat) }}$ | - | 1.5 | Vdc |
| $\begin{aligned} & \text { Base-Emitter On Voltage } \\ & \quad\left(\mathrm{I}_{\mathrm{C}}=100 \mathrm{mAdc}, \mathrm{~V}_{\mathrm{CE}}=5.0 \mathrm{Vdc}\right) \end{aligned}$ | $\mathrm{V}_{\mathrm{BE}}$ | - | 2.0 | Vdc |

SMALL-SIGNAL CHARACTERISTICS

| Current - Gain - Bandwidth Product (Note 4) <br> $\left(I_{C}=10 \mathrm{mAdc}, \mathrm{V}_{\mathrm{CE}}=5.0 \mathrm{Vdc}, \mathrm{f}=100 \mathrm{MHz}\right)$ | $\mathrm{f}_{\mathrm{T}}$ | MHz |
| :--- | :--- | :--- | :--- |

3. Pulse Test: Pulse Width $\leq 300 \mu \mathrm{~s}$, Duty Cycle $\leq 2.0 \%$.
4. $\mathrm{f}_{\mathrm{T}}=\left|\mathrm{h}_{\mathrm{fe}}\right| \bullet \mathrm{f}_{\text {test }}$.


Figure 1. Transistor Noise Model

## MMBTA13L, SMMBTA13L, MMBTA14L, SMMBTA14L

NOISE CHARACTERISTICS
$\left(\mathrm{V}_{\mathrm{CE}}=5.0 \mathrm{Vdc}, \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}\right)$


Figure 2. Noise Voltage


Figure 4. Total Wideband Noise Voltage


Figure 3. Noise Current


Figure 5. Wideband Noise Figure

MMBTA13L, SMMBTA13L, MMBTA14L, SMMBTA14L

SMALL-SIGNAL CHARACTERISTICS


Figure 6. Capacitance


Figure 8. DC Current Gain


Figure 10. "On" Voltages


Figure 7. High Frequency Current Gain

Figure 9. Collector Saturation Region


Figure 11. Temperature Coefficients


Figure 12. Thermal Response


Figure 13. Active Region Safe Operating Area


Design Note: Use of Transient Thermal Resistance Data


SOT-23 (TO-236)
CASE 318-08
ISSUE AS
DATE 30 JAN 2018

## SCALE 4:1



NOTES:
IMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994
. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

|  | MILLIMETERS |  |  | INCHES |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| DIM | MIN | NOM | MAX | MIN | NOM | MAX |
| A | 0.89 | 1.00 | 1.11 | 0.035 | 0.039 | 0.044 |
| A1 | 0.01 | 0.06 | 0.10 | 0.000 | 0.002 | 0.004 |
| b | 0.37 | 0.44 | 0.50 | 0.015 | 0.017 | 0.020 |
| $\mathbf{c}$ | 0.08 | 0.14 | 0.20 | 0.003 | 0.006 | 0.008 |
| D | 2.80 | 2.90 | 3.04 | 0.110 | 0.114 | 0.120 |
| E | 1.20 | 1.30 | 1.40 | 0.047 | 0.051 | 0.055 |
| e | 1.78 | 1.90 | 2.04 | 0.070 | 0.075 | 0.080 |
| L | 0.30 | 0.43 | 0.55 | 0.012 | 0.017 | 0.022 |
| L1 | 0.35 | 0.54 | 0.69 | 0.014 | 0.021 | 0.027 |
| $\mathbf{H E}_{\mathbf{E}}$ | 2.10 | 2.40 | 2.64 | 0.083 | 0.094 | 0.104 |
| T | $0^{\circ}$ | --- | $10^{\circ}$ | $0^{\circ}$ | --- | $10^{\circ}$ |

GENERIC
MARKING DIAGRAM*

RECOMMENDED SOLDERING FOOTPRINT


DIMENSIONS: MILLIMETERS


XXX = Specific Device Code
M = Date Code

- = Pb-Free Package
*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " $\quad$ ", may or may not be present.


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